

# National Institute of Technology Silchar

#### Silchar - 788010, Assam.

### Advertisement for Ph.D. admission for January to June 2026 session

No.: Dean (RC)/105/2026-27/1

Date: 15.10.2025

Applications are invited for admission into **Ph.D. programme** in the following departments with the area/specializations and admission group as mentioned in the table for the session **January-June 2026.** 

### **ADMISSION GROUP:**

There are two Groups of admission to a Ph.D. Program: 1. Group A (With Fellowship) 2. Group B (Without Fellowship)

**GROUP A:** Ph.D. Program - Regular Category who may receive fellowship from the MoE / CSIR / UGC or any other recognized funding agency.

Fellowship: As per MoE / CSIR / UGC guidelines.

Research Fellowship is available to the scholars who are admitted to Ph.D. programmes in different departments subject to the availability as stipulated by Ministry of Education. The award and renewal of the fellowship is as per the guidelines issued by MoE, from time to time.

In case of students, who secure a new job or otherwise wish to move outside the institute and end their doctoral program prematurely, need to refund any scholarship received.

### Eligibility for application in GROUP A:

All the shortlisted candidates for Group-A must appear the Centralized Written test at NIT Silchar in addition to the following eligibility criteria.

- 1. Students for admission into Ph.D. Programs in Engineering Departments must satisfy one of the following criteria:
  - i) M.E. / M. Tech. or equivalent with GATE / NET qualification/ Appropriate National Level Examination (Centralized Written test at NIT Silchar) in an appropriate area with a minimum CPI of 6.5 (on a 10 point scale) or equivalent (60% of marks). For SC/ST/PwD candidates, a minimum CPI of 6.0 (on a 10 points scale) or equivalent (55% of marks).
  - ii) B.E./B. Tech. with an excellent academic record with valid GATE score and with a CPI of at least 8.0 (on 10 point scale) or equivalent (75% of marks). For graduates from IITs/NITs, the minimum CPI requirement is 7.0 (on 10 point scale). For SC/ST/PwD candidates, there is a relaxation of 0.5 CPI or 55% of marks.
- 2. Students for admission into the Ph.D. Programs in Science departments must have a Master degree in the relevant discipline with a GATE/ UGC/ CSIR/NBHM/ NET score and Appropriate National Level Examination (Centralized Written test at NIT Silchar) for admission with a minimum CPI of 6.5 (on a 10 point scale) or equivalent (60% of marks). For SC/ST/PwD candidates, a minimum CPI of 6.0 (on a 10 point scale) or equivalent (55% of marks) with a GATE / UGC / CSIR / NBHM / NET score is required for admission.
- 3. Students for admission into the Ph.D. Programs in Department of Management Studies must have a Master's degree in Business Administration or Master degree in Engineering/ Technology with a minimum CPI of 6.5 (on a10 point scale) or equivalent (60% of marks) or Master degree in other disciplines with a minimum CPI of 6.5 (on a 10 point scale) or equivalent (60% of marks). For SC/ST/PwD candidates, a minimum CPI of 6.0 (on a 10point scale) or equivalent (55% of marks) is required. A score in NET /GATE/UGC and Appropriate

National Level Examination (Centralized Written test at NIT Silchar) is required for all.

4. Students for admission into the Ph.D. Programs in Department of Humanities and Social Sciences (HSS) must have a Master degree in any relevant field with a minimum CPI of 6.5 (on a10 point scale) or equivalent (60% of marks) or Master degree in other disciplines with a minimum CPI of 6.5 (on a10 point scale) or equivalent (60% of marks). For SC/ST/PwD candidates, a minimum CPI of 6.0 (on a10 point scale) or equivalent (55 % of marks) is required. As score in NET/GATE/UGC and Appropriate National Level Examination (Centralized Written test at NIT Silchar) is required for all.

GROUP B: Ph.D. Program—No financial assistance or stipend by NIT Silchar will be provided for this GROUP. There are six categories under this GROUP:

- I) **Regular** The regular students are those who work full-time for their Ph.D. and self financed.
- II) **Sponsored** who are employed in a Central/ State Govt. Departments /PSUs /Reputed Educational Institutes/ Research organizations/ Reputed Industries for doing research in the Institute on a full-time basis. He/ She should have at least two years of working experience in the respective field before last date of application. The candidate must submit the filled-in sponsorship letter (FORM I) from the employer with the application for admission. He / She shall not be entitled to any financial support from the Institute.
- III) Part-Time This category refers to the candidates who are professionally employed personnel. They have to stay in the Institute/around the Institute at least during the period of course work so that they can attend regular classes as per the Institute academic norm. The applicant must be an employee of a State/Central Govt. Departments/ PSUs/Reputed Educational Institutes/Research organizations/ Reputed Industries at the time of admission having at least one year experience in the discipline in which admission is sought. No financial assistance shall be provided by the Institute to such students. A No Objection Certificate from the Head of the Institute/Organization, in which he/she is employed, must been closed with application in FORM II.
- IV) Institute Employees Employees of NIT Silchar. A No Objection Certificate from the concerned Head of the Department and the Director must been closed with application form (FORM II-B).
- V) **Project Staff** –This category refers to the candidates who work on sponsored projects in the Institute. A No Objection Certificate from the Principal Investigator of the concerned project and Dean(R &C) must be enclosed with application form (FORM II-A).
- VI) **Sponsored (External Registration)** Candidates employed in R&D organizations/educational Institutes having adequate research facilities. Sponsorship certificate (FORM III) from the Head of the organization where the candidate is employed must be enclosed at the time of application.

### Eligibility for application in GROUP B:

All the shortlisted candidates for Group-B must appear the Centralized Written test at NIT Silchar in addition to the following eligibility criteria.

# **Engineering Departments:**

- 1. Students for admission into Ph.D. Programs in Engineering Departments must satisfy one of the following criteria:
  - M.E/M. Tech. or equivalent in an appropriate area with a minimum CPI of 6.5 (on a10 point scale) or equivalent (60% of marks). For SC/ST/PwD candidates, a minimum CPI of 6.0 (on a 10 point scale) or equivalent (55% of marks).

# **Science Departments:**

Students for admission into the Ph.D. Programs in Science departments must have a Master degree in
the relevant discipline with a minimum CPI of 6.5 (on a10 point scale) or equivalent (60% of marks).
For SC/ST/PwD candidates, a minimum CPI of 6.0 (on a 10 point scale) or equivalent (55% of marks)
is required.

# **Department of Management Studies:**

Students for admission into the Ph.D. Programs in Department of Management Studies must have a
Master Degree in Business Administration or Master Degree in relevant disciplines with a minimum
CPI of 6.5 (on a 10 point scale) or equivalent (60% of marks). For SC/ST/ PwD candidates, a minimum
CPI of 6.0 (on a10 point scale) or equivalent (55% of marks) is required.

# **Department of Humanities and Social Sciences (HSS)**

1. Students for admission into the Ph.D. Programs in Department of Humanities and Social Sciences (HSS) must have a Master degree in relevant field with a minimum CPI of 6.5 (on a10 point scale) or equivalent (60% of marks). For SC /ST/ PwD candidates, a minimum CPI of 6.0 (on a 10 point scale) or equivalent (55 % of marks) is required.

### **APPLICATION PROCEDURE**

The applicant can apply for the PhD program through the online application portal available at <a href="https://admission.nits.ac.in/">https://admission.nits.ac.in/</a> (else, copy the link and paste in the browser)

A Processing Fee of **Rs.1000**/- (for Open/OBC) or **Rs.500/-** (for SC/ST/ PwD/EWS) must be paid via online payment and steps for online payment is as follows:

- 1. www.onlinesbi.sbi
- 2. State Bank Collect (SB Collect).
- 3. Accept and proceed.
- 4. State of Institute>Assam.
- 5. Type of Institute>Educational institute>Go.
- 6. Educational Institutions Name>Select online fee collection account NIT Silchar>Submit.
- 7. Select payment category as "Processing fee for PhD Admission".
- 8. Fill the required information and submit.

The payment reference number and date of payment to be mentioned in the online application form, otherwise the application form will be treated as cancelled.

The applicant must upload all relevant self-attested documents, in connection with the credentials claimed by the applicant in pdf format.

The final pdf copy of the Application form is mandatory to email to **phd\_admission@nits.ac.in** on or **before** 13.11.2025. Subject line should be "Application for Ph.D. program-Name of the department (applying for)-Group A /Group B". No need to send the hard copy of the Application form.

The candidates are advised to give their latest contact numbers/e-mail ids in the application form. The Institute reserves the right to reject any or all applications or it may amend any of the clauses above as per orders of the competent authority/Government of India.

The result will be available in the website.

### **Important Dates:**

(i)	Last date of submission of form to the Institute:	13.11.2025
(ii)	Date of publication of Shortlisted candidate for interview & written test	25.11.2025
(iii)	Date of interview & written test by the department	11.12.2025
		12.12.2025
(iv)	Date for publication of provisionally selected candidates for admission	19.12.2025
(v)	Date of Registration	05.01.2026
		-
		07.01.2026

## **Selection Procedure:**

Selection process will comprise of following steps:

- Shortlisting will be made by the department on the basis of academic performance (starting from Class X onwards).
- All shortlisted candidates (Group-A and Group-B) need to appear for a Centralized Written test at NIT
  Silchar for the respective department as per the GATE/NET/UGC syllabus and followed by personal
  interview at the respective departments.
- Mere qualifying the written test and interview will not bestow confirmation of selection for the Ph.D. program at NIT Silchar.

## **GENERAL TERMS AND CONDITIONS**

- 1. The Institute reserves the right to cancel the candidature without assigning any reason thereof.
- 2. The prescribed qualification is minimum and mere possession of the same does not entitle candidates to be called for written test and interview.
- 3. No correspondence will be entertained from any candidates who have not been shortlisted for centralized written test.
- 4. Canvassing in any form will resulting qualification of candidature.
- 5. Legal disputes, if any, will be restricted within the jurisdiction of Silchar Court only.
- 6. Candidates should submit their application form along with all supporting documents duly self-attested at the time of verification.
- 7. All reserved category candidates shall be required to submit self-attested copies of latest Caste certificate issued by competent authority.
- 8. Candidates must produce original mark sheets and certificates during document verification if called for written test.
- 9. Candidates appearing for final year ME / M.Tech. / M Sc. / MA / MBA are also eligible to apply. However, their final result must be published on or before the final admission.
- 10. The date of written test, interview and provisional selection list will be published in the institute website including waitlisted candidates and the period of Registration will be published as per the above date.
- 11. Candidates are requested to check the institute website regularly for updates.

- 12. Hostel accommodation is subject to availability.
- 13. Candidates are requested to provide their active email Id/mobile phone numbers/land line phone numbers in the application form for easy contact.
- 14. No TA/DA will be paid for attending the Centralized written test at NIT Silchar.

# Department wise area of research

Department	Area of Research	Group
	Transportation Engineering and Planning	
	Traffic Engineering and Safety	
	Pavement Materials and Design	
<b>5</b> 0	Structural Engineering	A&B
erir	Structural Dynamics and Earthquake Engineering	ACD
Civil Engineering	Civil Engineering Materials	
E	Geotechnical Engineering	
Xivil	Geotechnical Earthquake Engineering	
<b>O</b>	Water Resources Engineering	
	Coastal Engineering	
	Remote Sensing and GIS	
	Environmental Engineering	
	Artificial Intelligence, Machine Learning, and NLP	
ring	Speech Processing	
neeı	Image Processing	A & B
<sup>(</sup> ngi	Mathematical Imaging	1142
nd F	Digital Geometry	
Computer Science and Engineering	Wearable Sensor Data Analysis	
cien	Computer Network	
r. S		
pute	Distributed Computing	
<b>Mo</b>	Optimization	
0	• Security	
	Cellular Network (5G/6G)	
	Semiconductor and Nano Technologies	
50	Micro/Nanoelectronic Devices, Circuits & Systems	
erin	Nanotechnology & Photonics	
gine	Advanced Semiconductor Devices & Memory Technologies	
En	Analog, Digital & Mixed-Mode VLSI Design, Embedded Systems  • Intelligent Microsystems & Energy Technologies	
tion	MEMS/NEMS  MEMS/NEMS	
nica	Solar Photovoltaics & Energy Harvesting	
in m	Robotics & IoT	
Om	Communication and Networking Technologies	A&B
Electronics & Communication Engineering	5G/6G & Beyond, RF, THz, and Millimetre-Wave Systems	
nics	Antennas, Microwave Engineering & Metamaterials Wireless, Cognitive Radio & Sensor Networks	
tro	Green, Optical & Massive/Cooperative MIMO Communications	
Elec	Intelligent Signal and Information Processing	
	Signal, Speech, Image & Video Processing	
	Biomedical Signal and Image Processing Computer Vision & Medical Imaging	

	Machine Learning & Soft Computing		
Electrical Engineering	<ul> <li>Power and Energy System Engineering</li> <li>Control Systems Engineering, Drone Technology &amp; Robotics</li> <li>Power Electronics and Drives</li> <li>VLSI, Embedded System and Image Processing</li> <li>High Volatage Engineering</li> <li>Semiconductor Devices, modelling and simulation, Nano electronics and nanomaterials (DFT based studies)</li> <li>Electric Vehicles, Batteries and Cyberphysical Systems</li> <li>Energy Storage and Renewable Energy Systems</li> <li>Biomedical Engineering</li> <li>AI applications in all domain of Electrical Engineering</li> <li>Smart Grid Technology, Microgrid and Energy Pricing</li> </ul>		
Mechanical Engineering   Electronics and Instrumentation Engineering	<ul> <li>Smart Grid Technology, Microgrid and Energy Pricing</li> <li>Automation, Control, Robotics, and Systems.</li> <li>Biomedical Engineering.</li> <li>Communication Systems.</li> <li>Signal and Image Processing.</li> <li>Energy Storage &amp; Renewable Energy Systems</li> <li>Systems Modelling, Identification and Estimation</li> <li>Microelectronics &amp; Nano Electronics.</li> <li>Drone Technology.</li> <li>Electric vehicle, Batteries and cyberphysical Systems</li> <li>Condition monitoring and fault diagnosis</li> <li>Semiconductor Device Modeling and Simulation- Bio Sensors, Wearable Electronics and Antennas, Thin Film Supercapacitors</li> <li>AI, Analytics and Computation in Engineering.</li> <li>Design.</li> <li>Manufacturing Sciences.</li> <li>Materials Engineering.</li> <li>Renewable Energy</li> <li>Thermal Engineering</li> </ul>		
Chemistry	<ul> <li>Organic Chemistry</li> <li>Inorganic Chemistry</li> <li>Renewable Energy</li> <li>Physical Chemistry</li> <li>Environmental/Analytical Chemistry</li> <li>Nanoscience and Nanotechnology</li> <li>Computational Chemistry and Molecular Modeling</li> <li>Biomass and Bioenergy</li> <li>Two-dimensional (2D) and three-dimensional (3D) porous materials and applications</li> <li>Catalysis/Photocatalysis</li> <li>Waste Management and Recycling</li> <li>Drug/ligand-Protein Interaction</li> <li>Nano electronics and nanomaterials(DFT based studies)</li> </ul>	A&B	

	Experimental Condensed Matter P.	hysics:	A&B
	Low dimensional materials, Perovskites		MAD
	Memristive devices for neuromorphic computing		
	Energy storage and harvesting devices: Solar Photovoltaics, Solar Energy, metal air batteries, nanogenerator		
	Photocatalytic hydrogen Production		
	Single crystals, non-linear optics		
×	Dielectrics and ferroelectrics		
Physics	Theoretical and Computational Co.	ndensed Matter Physics	
百	Quantum Materials, Quantum Anomaly i	n Topological Semimetals	
	Quantum Geometry induced Nonlinear Transport, Topological Superconductivity		
	Density functional theory, Non-hermitian phenomena in candensed matter physics		
	Theoretical High Energy Physics	•	
	High energy phenomenology, B anamolic	es, dark matter, neutrino physics	
	Quantum Field Theories, String Theory a	* *	
	Gauge/Gravity Duality,Black HoleThern	•	
	General Theory of Relativity and Cosmology		
	Differential Equations, Numerical Methods, Mathematical Modelling	Numerical Methods for Engineering Problems	A&B
	Single and Multi-objective	• Fuzzy set theory and application	
	Optimization, Networking Optimization, Multi-criteria decision	Biomechanics; Fluid Mechanics;     Differential Equations	
so	<ul> <li>making, Optimization in AI and ML</li> <li>Mathematical modelling, CFD</li> </ul>	• Functional Analysis, Operator Theory, and Matrix Analysis	
thematics	<ul><li>(Computational Fluid Dynamics)</li><li>Fuzzy optimization, integro differential equations with</li></ul>	Operations Research & Optimization Techniques, Mathematical Modelling,	
Matho	application, inverse eigenvalue	Elastodynamics	
	problem	Complex Analysis, Number theory	
	Computational Fluid Dynamics,	cryptography	
	Mathematical modelling in micro and nanofluidics.	• Fuzzy Set theory and its applications	
	<ul> <li>Finite Element Methods (FEMs) for Differential Equations, Numerical Analysis.</li> </ul>	Partition Theory	
931	Macro and micro economics	Eco-literature	A&B
cien	• Financial, Environmental,	<ul> <li>Folklore Studies</li> </ul>	
ial S	Agricultural & Behavioural	Indigenous Studies	
Soci	Economics	Women's writing	
pur	Sports Economics	<ul> <li>North East Literature</li> </ul>	
ties :	Literary and Translation Studies	Critical media studies	
anit	Translation and Colonialism		
Humanities and Social Science	Literary Historiogrpahy	Digital Humanities	
<del></del>	1947 Partition Studies	• Urban Studies.	

	<ul><li>Service Marketing</li><li>Tourism Management</li></ul>	<ul> <li>Financial Accounting</li> <li>Financial Modelling</li> </ul>
	Marketing Management	Portfolio Optimization
	Sustainability	• Econometrics
Š	Marketing Analytics	Human Resource Management
Studies	Neuromarketing	Organisational Behaviour
	Strategic Management	Human Resource Analytics
Management	Global Business and     International Management	<ul> <li>Industrial Relations and Labour Laws</li> </ul>
/Ian	Innovation and Technology	General Management
	Management	IPR Management and
	Financial Management	Commercialization
	Behavioural Finance	IP and Technology Transfer
	• FinTech	IP in Digital & Internet Law
	Entrepreneurship	IP for Start Up and     Entrepreneurship

### FORM I

## SPONSORSHIP LETTER FOR FULL-TIME PH.D. PROGRAM

(Should be typed on the letter head of the sponsoring organization)

Reference No.

Date:

To

The Director National Institute of Technology Silchar Assam788010

Sub: Sponsoring an Employee for Ph.D. Program

Dear Sir,	
We here by sponsor the candidate	ure of Mr./Ms./Mrs
Designation:	_who is a regular employee in our organization, for joining Ph.D. Program
in the department of	at your Institute as a full-time student.
It is certified that he/she has comple	eted two years of service in our organization as a regular employee.
He/she has gained experience in the	e field(s)
If selected, we shall relieve him/he	r from his/her duties to join the program during the first three years of the Ph.D
Program.	

Signature and Seal of the Sponsoring Authority

Signature and Seal of the Sponsoring Authority

## FORM II

# No Objection Certificate for Part-Time Students

	(Should be typed on the lette	er head of the sponsoring	g organization)	
		Refe	erence No.	
То		Date	e:	
10	The Director			
	National Institute of Technology Silchar Assam 788010			
Sub: N	o objection Certificate			
Dear Si	r,			
	ve no objection if Mr./Mrs/Msan employee/project staff in our orga:		_	
	at			
It is cer	tified that he/she has completed one year of	service in our organizati	ion. If selected, we shall sanction	
him/he	r leave of absence to attend classes/research	work at NIT Silchar dur	ring the Ph.D. program.	



## NATIONAL INSTITUTE OF TECHNOLOGY SILCHAR

## FORM II-A

# No Objection Certificate for Admission into Ph.D. Program (Project Staff)

То	The Director National Institute of Technology Silchar Assam 788010	Reference No. Date:	
Sub: N	o objection Certificate		
Dear Si	ir,		
departn	ve no objection if Mr./Mrs/Msa project staff, under the project: (title of, in the department of  ment of  d that the said project shall continue for one more year	of the project), Sanction letter no, is admitted to the Ph.D. Program of NIT Silchar as a Group-B Regular studen	in the
If selec	ted, we shall allow him/her to attend classes/research  D. program without affecting normal project work assi	work under the said project at NIT Silchar of	during
Signat	ture of Project Investigator (Name)	Signature of Dean (R & C	")



## NATIONAL INSTITUTE OF TECHNOLOGY SILCHAR

## FORM II-B

# No Objection Certificate for Admission into Ph.D. Program (Institute Employee)

- FOLIEGIA	No Objection Certificate for A	to Objection Certificate for Admission into Ph.D. Program (Institute Employee)	
		Reference No.	
		Date:	
It is certified that we	have no objection if Mr./Mrs/Ms.		
Designation:		,a (regular / contractual) employee	
of this Institute, wor	king in the department of.		
is admitted into the l	Ph.D. Program in the department of	f	
at this Institute as a J	part-time student.		
If selected, he/she sh	nall be allowed to attend classes/res	search work without affecting normal duties assigned to	
him/her.			
Signature of Head	(Department:)	Signature of Director	

### FORM III

## **Sponsorship Certificate for External Registration**

(This should be typed on the letter head of the sponsoring organization)

Reference No. Date:

То

The Director National Institute of Technology Silchar Assam 788010

	Assam 788010	
Sul	b: Sponsoring an Employee for Ph.D. Program under external registration	
1.	Name of the sponsoring organization:	
2.	Address:	
3.	Name of the Candidate:	
4.	Designation of the applicant:	
5.	Present status of the applicant:	
	(regular/year of completed service)	
6.	Department/Division/Center where research work is proposed to be done:	
7.	Name of the Local (Joint Supervisor):	
	(Bio-data of the Local supervisor (Joint Supervisor) to be enclosed giving deta	ails of designation,
	qualification, research experience etc.)	
8.	Details of relevant facilities which will be made available to the candidate:	
9.	Statement of Local supervisor (Joint Supervisor):	
Dea	ar Sir,	
If N	Mr./Mrs./Msis admi	itted to the Ph.D. program at
	tional Institute of Technology Silchar, I agree to supervise his/her research program NIT Silchar.	m jointly with the Supervisor
110		w (I start Company)
	Signature of Local supervisor	•
	If Mr./Mrs./Ms	
_	gram, we agree to relieve him / her to reside at NIT Silchar / around NIT Silchar	r during one/ two semester(s)
of l	nis /her Ph.D. program to complete his/her course work requirement.	
	Mr./Mrs./Ms	will be
itte	d to carry out research at our organization under the guidance of Dr.	Leading to

Ph.D. degree from NIT Silchar. Necessary facilities will be provided for this purpose.

Signature and Seal of the Sponsoring Authority